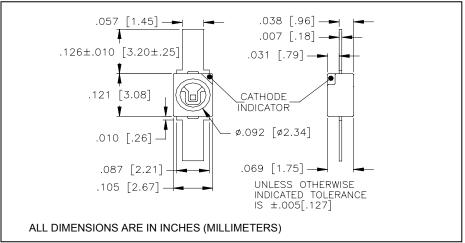
CLE300F

Aluminum Gallium Arsenide IRED Flat Lead PLCC Package



May, 2003





features

- Flat lead PLCC package
- ±50° emission angle
- 850 nm peak wavelength
- RoHS compliant

description

The CLE300F is an 850nm high output infrared emitting diode chip featuring current AlGaAs technology. It is mounted in a compact, embedded leadframe package with flying lead configuration and overcoated with clear epoxy to provide a wide emission pattern. Contact Clairex for alternative wavelength emitter chips, different lenses and lead configurations.

absolute maximum ratings (T_A = 25°C unless otherwise stated)

storage temperature	40°C to +125°C
operating temperature	40°C to +125°C
lead soldering temperature ⁽¹⁾	260°C
continuous forward current ⁽²⁾	50mA
peak forward current (1.0ms pulse width, 10% duty cycle)	1A
reverse voltage	5V
reverse voltagecontinuous power dissipation ⁽³⁾	80mW

notes:

- 1. 0.06" (1.5mm) from case for 5 seconds maximum.
- 2. Derate linearly 0.40mA/°C from 25°C free air temperature to $T_A = +125$ °C.
- 3. Derate linearly 0.64mW/°C from 25°C free air temperature to $T_A = +125$ °C.

electrical characteristics (T_A = 25°C unless otherwise noted)

symbol	parameter	min	typ	max	units	test conditions
Po	Total power output	3.0	4.0	-	mW	I _F = 20mA
V_{F}	Forward voltage	-	1.4	1.6	V	I _F = 20mA
I _R	Reverse current	-	-	10	μΑ	V _R = 5V
λр	Peak emission wavelength	-	850	-	nm	I _F = 20mA
BW	Spectral bandwidth at half power points	-	60	-	nm	I _F = 20mA
θ_{HP}	Emission angle at half power points	-	100	-	deg.	I _F = 20mA
t _r	Radiation rise time ⁽⁴⁾	-	11	-	ns	I _{F(PK)} = 20mA
t _f	Radiation fall time ⁽⁴⁾	-	7.0	-	ns	I _{F(PK)} = 20mA

notes: 4. f = 100kHz, D.C. = 50%. Pulse generator t_f and $t_f < 200ps$.

Clairex reserves the right to make changes at any time to improve design and to provide the best possible

Revised 11/08/06

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